8-Channel Data Selector

The MC14512B is an 8-channel data selector constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. This data selector finds primary application in signal multiplexing functions. It may also be used for data routing, digital signal switching, signal gating, and number sequence generation.

Features

- Diode Protection on All Inputs
- Single Supply Operation
- 3-State Output (Logic "1", Logic "0", High Impedance)
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–power Schottky TTL Load Over the Rated Temperature Range
- Pb–Free Packages are Available*

MAXIMUM RATINGS (Voltages Referenced to VSS)

| Parameter | Symbol | Value | Unit |
|--|------------------------------------|----------------------------------|------|
| DC Supply Voltage Range | V _{DD} | -0.5 to +18.0 | V |
| Input or Output Voltage Range (DC or Transient) | V _{in} , V _{out} | –0.5 to V _{DD} + 0.5 | V |
| Input or Output Current (DC or Transient) per Pin | I _{in} , I _{out} | ±10 | mA |
| Power Dissipation, Per Package (Note 1) | PD | 500 | mW |
| Ambient Temperature Range | T _A | -55 to +125 | °C |
| Storage Temperature Range | T _{stg} | -65 to +150 | °C |
| Lead Temperature (8–Second Soldering) | ΤL | 260 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Temperature Derating: Plastic "P and D/DW"

Packages: – 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

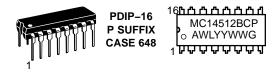
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques



ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS



| 1 1 | SOIC-16 D SUFFIX CASE 751B | 16 14512BG AWLYWW |
|-----------------------------|---|-----------------------------|
| A WL YY, Y WW G | = Assembly = Wafer Lot = Year = Work We = Pb-Free | tek |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Reference Manual, SOLDERRM/D.

PIN ASSIGNMENT

16 V_{DD} 15 DIS

14 🛛 Z

13] C 12] B

11 🛛 A

10 | INH

9 🛛 X7

X0 🛛 1 •

X1 [] 2 X2 [] 3

X3 🛛 4

X4 🛛 5

X5 🛛 6

X6 [] 7 V_{SS} [] 8

TRUTH TABLE

| С | В | Α | Inhibit | Disable | Z |
|---|---|---|---------|---------|----------------|
| 0 | 0 | 0 | 0 | 0 | X0 |
| 0 | 0 | 1 | 0 | 0 | X1 |
| 0 | 1 | 0 | 0 | 0 | X2 |
| 0 | 1 | 1 | 0 | 0 | Х3 |
| 1 | 0 | 0 | 0 | 0 | X4 |
| 1 | 0 | 1 | 0 | 0 | X5 |
| 1 | 1 | 0 | 0 | 0 | X6 |
| 1 | 1 | 1 | 0 | 0 | Х7 |
| х | Х | Х | 1 | 0 | 0 |
| Х | Х | Х | Х | 1 | High Impedance |

NOTE: X = Don't Care

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------------|----------------------|-----------------------|
| MC14512BCP | PDIP-16 | |
| MC14512BCPG | PDIP–16 (Pb–Free) | 25 Units / Rail |
| MC14512BD | SOIC-16 | |
| MC14512BDG | SOIC-16 (Pb-Free) | 48 Units / Rail |
| MC14512BDR2 | SOIC-16 | |
| MC14512BDR2G | SOIC-16 (Pb-Free) | 2500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC14512B

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| | | | | - 5 | 5°C | | 25°C | | 125 | S°C | |
|---|-----------|-----------------|------------------------|-----------------------------------|----------------------|-----------------------------------|--|----------------------|-----------------------------------|----------------------|----------|
| Characteristic | | Symbol | V _{DD} Vdc | Min | Max | Min | Typ (Note 2) | Max | Min | Max | Unit |
| Output Voltage V _{in} = V _{DD} or 0 | "0" Level | V _{OL} | 5.0 10 15 | - - - | 0.05 0.05 0.05 | _ _ _ | 0 0 0 | 0.05 0.05 0.05 | - - - | 0.05 0.05 0.05 | Vdc |
| $V_{in} = 0 \text{ or } V_{DD}$ | "1" Level | V _{OH} | 5.0 10 15 | 4.95 9.95 14.95 | _ _ _ | 4.95 9.95 14.95 | 5.0 10 15 | - - - | 4.95 9.95 14.95 | | Vdc |
| Input Voltage $(V_O = 4.5 \text{ or } 0.5 \text{ Vdc})$ $(V_O = 9.0 \text{ or } 1.0 \text{ Vdc})$ $(V_O = 13.5 \text{ or } 1.5 \text{ Vdc})$ | "0" Level | V _{IL} | 5.0 10 15 | - - - | 1.5 3.0 4.0 | _ _ _ | 2.25 4.50 6.75 | 1.5 3.0 4.0 | | 1.5 3.0 4.0 | Vdc |
| $(V_{O} = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_{O} = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_{O} = 1.5 \text{ or } 13.5 \text{ Vdc})$ | "1" Level | V _{IH} | 5.0 10 15 | 3.5 7.0 11 | | 3.5 7.0 11 | 2.75 5.50 8.25 | - - - | 3.5 7.0 11 | | Vdc |
| $\begin{array}{l} \text{Output Drive Current} \\ (\text{V}_{\text{OH}} = 2.5 \ \text{Vdc}) \\ (\text{V}_{\text{OH}} = 4.6 \ \text{Vdc}) \\ (\text{V}_{\text{OH}} = 9.5 \ \text{Vdc}) \\ (\text{V}_{\text{OH}} = 13.5 \ \text{Vdc}) \end{array}$ | Source | I _{ОН} | 5.0 5.0 10 15 | - 3.0 - 0.64 - 1.6 - 4.2 | - - - - | - 2.4 - 0.51 - 1.3 - 3.4 | - 4.2 - 0.88 - 2.25 - 8.8 | - - - - | - 1.7 - 0.36 - 0.9 - 2.4 | | mAd c |
| | Sink | I _{OL} | 5.0 10 15 | 0.64 1.6 4.2 | - - - | 0.51 1.3 3.4 | 0.88 2.25 8.8 | - - - | 0.36 0.9 2.4 | | mAd c |
| Input Current | | l _{in} | 15 | - | ± 0.1 | - | ±0.00001 | ± 0.1 | - | ± 1.0 | μAdo |
| Input Capacitance (V _{in} = 0) | | C _{in} | - | - | - | - | 5.0 | 7.5 | - | - | pF |
| Quiescent Current (Per Package) | | I _{DD} | 5.0 10 15 | - - - | 5.0 10 20 | _ _ _ | 0.005 0.010 0.015 | 5.0 10 20 | - - - | 150 300 600 | μAdo |
| Total Supply Current (Note (Dynamic plus Quiesce Per Package) (C _L = 50 pF on all outpu buffers switching) | nt, | IT | 5.0 10 15 | | | $I_{T} = (1$ | .8 μΑ/kHz) f .6 μΑ/kHz) f .4 μΑ/kHz) f | + I _{DD} | | | μAdo |
| 3–State Leakage Current | | I _{TL} | 15 | - | ± 0.1 | - | ± 0.0001 | ± 0.1 | - | ± 3.0 | μAdo |

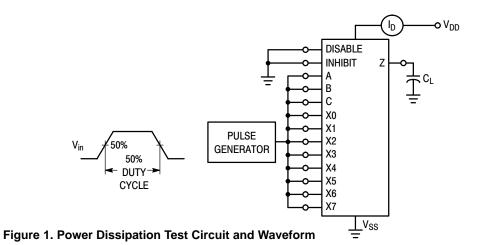
2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

Data labelled Typ is not to be used for design purposes but is interfaced as an indication of the iC's potential performance.
 The formulas given are for the typical characteristics only at 25°C.
 To calculate total supply current at loads other than 50 pF: I_T(C_L) = I_T(50 pF) + (C_L - 50) Vfk where: I_T is in μA (per package), C_L in pF, V = (V_{DD} - V_{SS}) in volts, f in kHz is input frequency, and k = 0.001.

SWITCHING CHARACTERISTICS (Note 5) (C_L = 50 pF, T_A = 25°C, See Figure 1)

| | | | All T | ypes | |
|---|--|-----------------|------------------------|-------------------|------|
| Characteristic | Symbol | V _{DD} | Typ (Note 6) | Max | Unit |
| Output Rise and Fall Time t_{TLH} , $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ t_{TLH} , $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ t_{TLH} , $t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$ | t _{TLH} , t _{THL} | 5.0 10 15 | 100 50 40 | 200 100 80 | ns |
| Propagation Delay Time (Figure 2) Inhibit, Control, or Data to Z | t _{PLH} | 5.0 10 15 | 330 125 85 | 650 250 170 | ns |
| Propagation Delay Time (Figure 2) Inhibit, Control, or Data to Z | t _{PHL} | 5.0 10 15 | 330 125 85 | 650 250 170 | ns |
| 3–State Output Delay Times (Figure 3) "1" or "0" to High Z, and High Z to "1" or "0" | t _{PHZ} , t _{PLZ} , t _{PZH} , t _{PZL} | 5.0 10 15 | 60 35 30 | 150 100 75 | ns |

The formulas given are for the typical characteristics only at 25°C.
 Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.



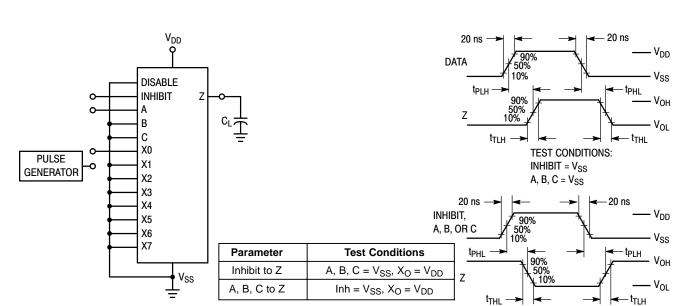


Figure 2. AC Test Circuit and Waveforms

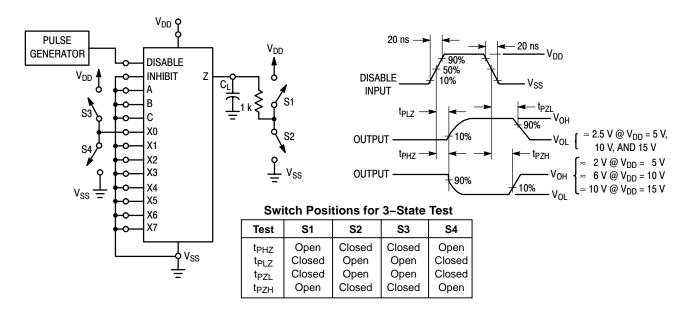
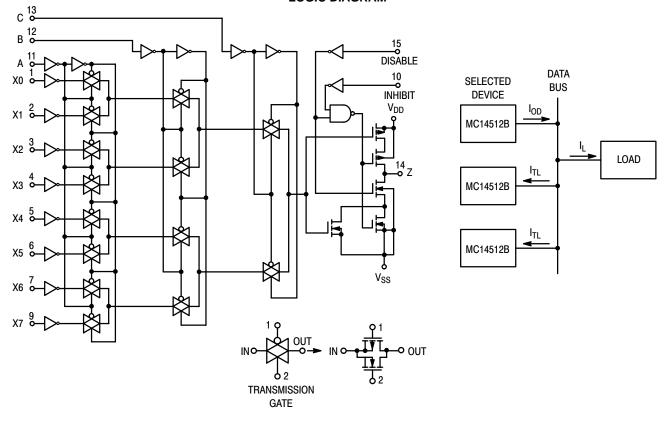


Figure 3. 3–State AC Test Circuit and Waveform

MC14512B

LOGIC DIAGRAM



3-STATE MODE OF OPERATION

Output terminals of several MC14512B 8–Bit Data Selectors can be connected to a single date bus as shown. One MC14512B is selected by the 3–state control, and the remaining devices are disabled into a high–impedance "off" state. The number of 8–bit data selectors, N, that may be connected to a bus line is determined from the output drive current, I_{OD} , 3–state or disable output leakage current, I_{TL} , and the load current, I_L , required to drive the bus line

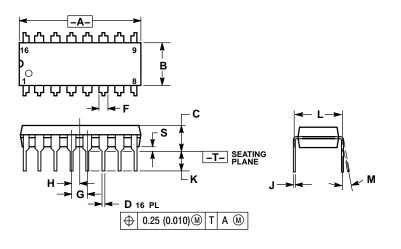
(including fanout to other device inputs), and can be calculated by:

$$N = \frac{I_{OD} - I_L}{I_{TL}} + 1$$

N must be calculated for both high and low logic state of the bus line.

PACKAGE DIMENSIONS

PDIP-16 CASE 648-08 ISSUE T

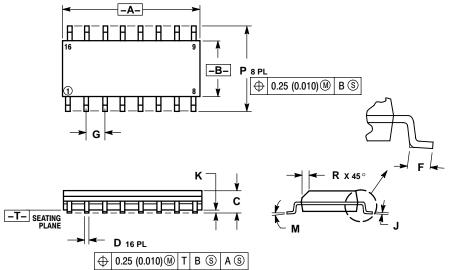


- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MODE ELASH

- MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL.

| | INC | HES | MILLIN | IETERS | | |
|-----|-------|-------|----------|--------|--|--|
| DIM | MIN | MAX | MIN | MAX | | |
| Α | 0.740 | 0.770 | 18.80 | 19.55 | | |
| В | 0.250 | 0.270 | 6.35 | 6.85 | | |
| С | 0.145 | 0.175 | 3.69 | 4.44 | | |
| D | 0.015 | 0.021 | 0.39 | 0.53 | | |
| F | 0.040 | 0.70 | 1.02 | 1.77 | | |
| G | 0.100 | BSC | 2.54 BSC | | | |
| н | 0.050 | BSC | 1.27 | BSC | | |
| J | 0.008 | 0.015 | 0.21 | 0.38 | | |
| κ | 0.110 | 0.130 | 2.80 | 3.30 | | |
| L | 0.295 | 0.305 | 7.50 | 7.74 | | |
| М | 0 ° | 10 ° | 0 ° | 10 ° | | |
| S | 0.020 | 0.040 | 0.51 | 1.01 | | |

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NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DED SIGN

- PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR
- PROTRUSION & DEES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| | MILLIN | IETERS | INC | HES |
|-----|--------|--------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 9.80 | 10.00 | 0.386 | 0.393 |
| В | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 | BSC | 0.050 | BSC |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| Μ | 0 ° | 7° | 0° | 7° |
| Ρ | 5.80 | 6.20 | 0.229 | 0.244 |
| B | 0.25 | 0.50 | 0.010 | 0.019 |

MC14512B

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